NSN 5961-00-755-6729

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No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-00-755-6729 **Inclosure Material:** Metal **Overall Length:** 0.340 inches **Overall Diameter:** 0.500 inches **Mounting Facility Quantity:** 2 **Internal Configuration:** Junction contact **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 500.0 collector to emitter reverse voltage and 350.0 collector to emitter voltage/static/base open and 4.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** Between 0.50 amperes source cutoff current and 1.00 amperes source cutoff current **Power Rating Per Characteristic:** 2.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Precious Material And Location:** Terminal surface gold **Precious Material:** Gold **Terminal Type And Quantity:** 2 uninsulated wire lead and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:**